## NSN 5962-01-081-9697

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## **Body Length:** 1.290 inches **Body Width:** 0.595 inches **Body Height:** 0.180 inches **Maximum Power Dissipation Rating:** 560.0 milliwatts **Operating Tempurature Range:** +0.0/+70.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Monolithic and hermetically sealed and positive outputs and w/buffered output and w/decoded output and programmable and programmed and w/enable **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 13 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 20.0 volts power source **Time Rating Per Chacteristic:** 450.00 nanoseconds propagation delay time, low to high level output Memory Device Type: Rom **Memory Capacity:** Unknown **Test Data Document:** 18323-7266a15 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a Unit Of Measure: **Demilitarization:** Yes - demil/mli

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